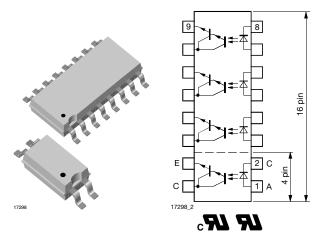
Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, Single/Quad Channel, Half Pitch Mini-Flat Package



www.vishay.com

DESCRIPTION

The TCMD1000, TCMD4000 consist of a photodarlington optically coupled to a gallium arsenide infrared-emitting diodes in either a 4 pin or 16 pin miniflat package.

The elements provide a fixed distance between input and output for highest safety requirements.

FEATURES

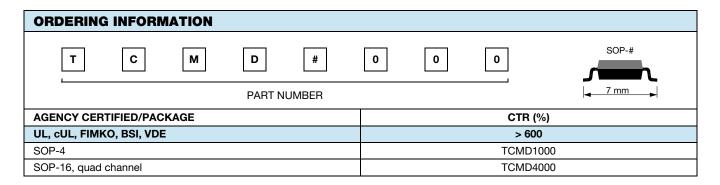
- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPICLATIONS

- Programmable logic
- Modems
- Answering machines
- General applications

AGENCY APPROVALS

- UL1577, file no. E76222 system code M, double protection
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5)
- FIMKO
- BSI



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL VALUE UNIT						
INPUT								
Reverse voltage		V _R	6	V				
Forward current		l _F	60	mA				
Forward surge current	t _P ≤ 10 µs	I _{FSM}	1.5	А				
Power dissipation		P _{diss}	100	mW				
Junction temperature		Tj	125	°C				





GREEN (5-2008)

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
OUTPUT		-					
Collector emitter voltage		V _{CEO}	35	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ι _C	80	mA			
Collector peak current	$t_P/T=0.5,t_P\leq 10\;ms$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
AC isolation test voltage (RMS)		V _{ISO} ⁽¹⁾	3750	V _{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 125	°C			
Soldering temperature ⁽²⁾		T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Related to standard climate 23/50 DIN 50014.

⁽²⁾ Wave soldering three cycles are allowed. Also refer to "Assembly Instruction" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 \degree C$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
input							
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V	
Junction capacitance	$V_R = 0 V, f = 1 MHz$	Cj		50		pF	
output							
Collector emitter voltage	I _C = 100 μA	V _{CEO}	35			V	
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V	
Collector dark current	$V_{CE} = 10 \text{ V}, I_F = 0, E = 0$	I _{CEO}			100	nA	
coupler							
Collector emitter saturation voltage	$I_{\rm F} = 20$ mA, $I_{\rm C} = 5$ mA	V _{CEsat}			1	V	
Cut-off frequency	$I_{F} = 10 \text{ mA}, V_{CE} = 5 \text{ V}, \\ R_{L} = 100 \ \Omega$	f _c		10		kHz	
Coupling capacitance	f = 1 MHz	C _k		0.3		pF	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	V _{CE} = 2 V, I _E = 1 mA	TCMD1000	CTR	600	800		%
IC/IF	$v_{CE} = 2 v$, $i_F = 1 mA$	TCMD4000	CTR	600			%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \; V, \; I_C = 10 \; mA, \; R_L = 100 \; \Omega \\ (see \; figure \; 1) \end{array}$	tr		300		μs
Turn-off time	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \; V, \; I_{C} = 10 \; mA, \; R_{L} = 100 \; \Omega \\ & (\text{see figure 1}) \end{array}$	t _{off}		250		μs

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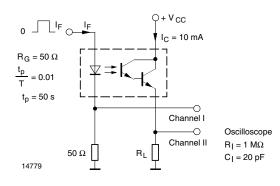


Fig. 1 - Test Circuit, Non-Saturated Operation

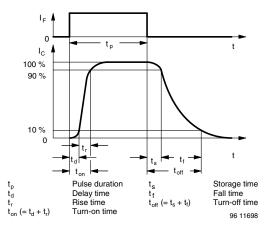


Fig. 2 - Switching Times

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification	IEC 68 part 1			40/110/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			6000			V	
V _{IORM}			707			V	
P _{SO}					265	mW	
I _{SI}					130	mA	
T _{SI}					150	°C	
Creepage distance			5			mm	
Clearance distance			5			mm	
Insulation thickness, reinforce rated	per IEC 60950 2.10.5.1		0.4			mm	

Note

• As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



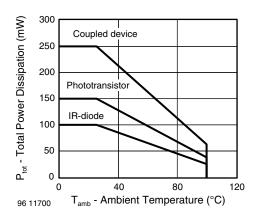


Fig. 3 - Forward Voltage vs. Ambient Temperature

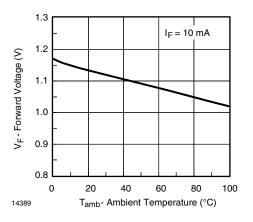


Fig. 4 - Forward Voltage vs. Ambient Temperature



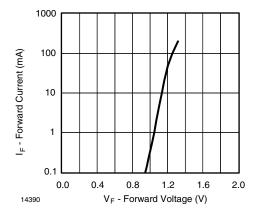


Fig. 5 - Forward Current vs. Forward Voltage

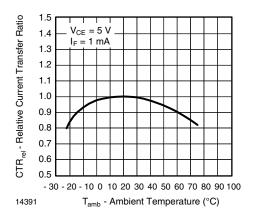


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

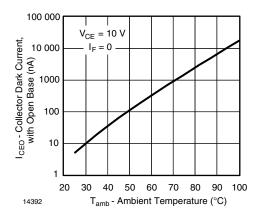


Fig. 7 - Collector Dark Current vs. Ambient Temperature

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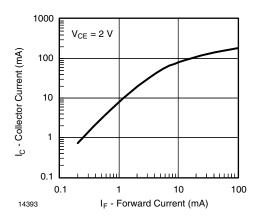


Fig. 8 - Collector Current vs. Forward Current

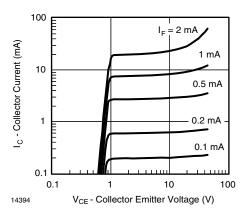


Fig. 9 - Collector Current vs. Collector Emitter Voltage

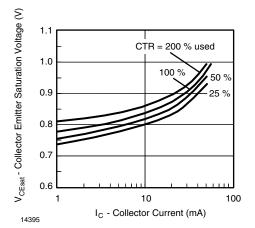


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

4 For technical questions, contact: <u>optocoupleranswers@vishay.com</u>

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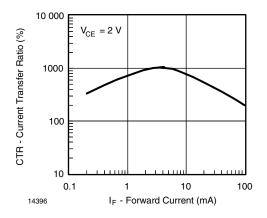
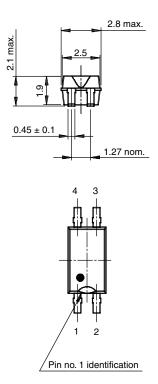
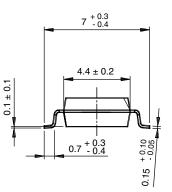


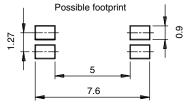
Fig. 11 - Current Transfer Ratio vs. Forward Current

PACKAGE DIMENSIONS in millimeters

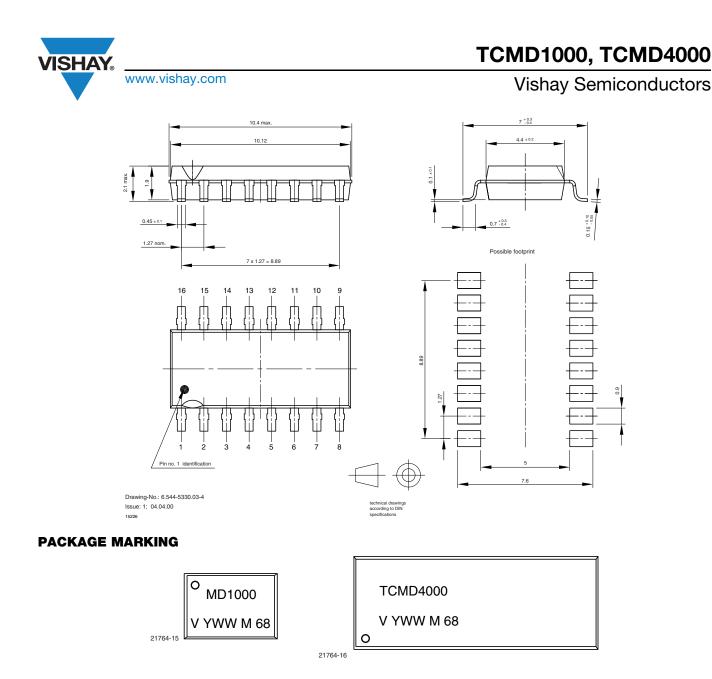


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